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### CMOS ASYNCHRONOUS FIFO 2,048 x 9, 4,096 x 9 8,192 x 9, 16,384 x 9 32,768 x 9 and 65,536 x 9

IDT7203 IDT7204 IDT7205 IDT7206 IDT7207 IDT7208

# FEATURES:

- First-In/First-Out Dual-Port memory
- 2,048 x 9 organization (IDT7203)
- 4,096 x 9 organization (IDT7204)
- 8,192 x 9 organization (IDT7205)
- 16,384 x 9 organization (IDT7206)
- 32,768 x 9 organization (IDT7207)
- 65,636 x 9 organization (IDT7208)
- High-speed: 12ns access time
- Low power consumption
  - Active: 660mW (max.)
  - Power-down: 44mW (max.)
- · Asynchronous and simultaneous read and write
- Fully expandable in both word depth and width
- Pin and functionally compatible with IDT720X family
- Status Flags: Empty, Half-Full, Full
- · Retransmit capability
- High-performance CMOS technology
- · Military product compliant to MIL-STD-883, Class B
- Standard Military Drawing for #5962-88669 (IDT7203), 5962-89567 (IDT7203), and 5962-89568 (IDT7204) are listed on this function

# FUNCTIONAL BLOCK DIAGRAM

- Industrial temperature range (-40°C to +85°C) is available (plastic packages only)
- · Green parts available, see ordering information

# **DESCRIPTION:**

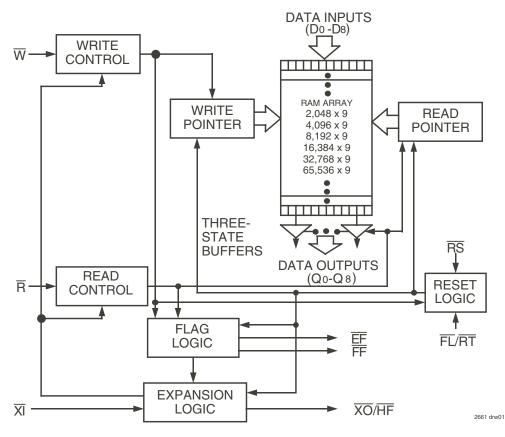
The IDT7203/7204/7205/7206/7207/7208 are dual-port memory buffers with internal pointers that load and empty data on a first-in/first-out basis. The device uses Full and Empty flags to prevent data overflow and underflow and expansion logic to allow for unlimited expansion capability in both word size and depth.

Data is toggled in and out of the device through the use of the Write  $(\overline{W})$  and Read  $(\overline{R})$  pins.

The device's 9-bit width provides a bit for a control or parity at the user's option. It also features a Retransmit ( $\overline{RT}$ ) capability that allows the read pointer to be reset to its initial position when  $\overline{RT}$  is pulsed LOW. A Half-Full Flag is available in the single device and width expansion modes.

These FIFOs are fabricated using IDT's high-speed CMOS technology. They are designed for applications requiring asynchronous and simultaneous read/writes in multiprocessing, rate buffering and other applications.

Military grade product is manufactured in compliance with the latest revision of MIL-STD-883, Class B.

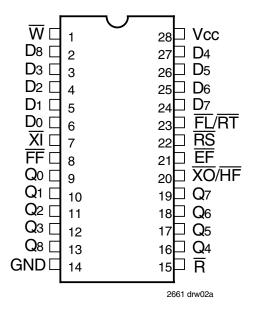


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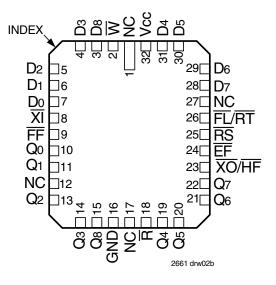
### **COMMERCIAL, MILITARY AND INDUSTRIAL TEMPERATURE RANGES**

### **JUNE 2009**

# **PIN CONFIGURATIONS**



TOP VIEW



TOP VIEW

	Reference	Order	Device
Package Type	Identifier	Code	Availability
PLASTIC DIP	P28-1	Р	All devices
PLASTIC THIN DIP	P28-2	TP	All except IDT7207/7208
CERDIP	D28-1	D	All except IDT7208
THIN CERDIP	D28-3	TD	Only for IDT7203/7204/7205
SOIC	SO28-3	\$0	Only for IDT7204

PackageType	Reference Identifier	Order Code	Device Availability
PLCC	J32-1	J	All devices
LCC <sup>(1)</sup>	L32-1	L	All except IDT7208

NOTE:

1. This package is only available in the military temperature range.

### **ABSOLUTE MAXIMUM RATINGS**

Symbol	Rating	Com'l & Ind'l	Military	Unit
VTERM	Terminal Voltage with Respect to GND	-0.5 to +7.0	–0.5 to +7.0	V
TSTG	Storage Temperature	–55 to + 125	-65 to +155	°C
Ιουτ	DC Output +Current	-50 to +50	-50 to +50	mA

### NOTE:

 Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

# RECOMMENDED DC OPERATING CONDITIONS

Symbol	Parameter	Min.	Тур.	Max.	Unit
Vcc	Supply Voltage Commercial/Industrial/Military	4.5	5.0	5.5	V
GND	Supply Voltage	0	0	0	V
VIH <sup>(1)</sup>	Input High Voltage Commercial/Industrial	2.0			V
VIH <sup>(1)</sup>	Input High Voltage Military	2.2	_	_	V
VIL <sup>(2)</sup>	Input Low Voltage Commercial/Industrial/Military			0.8	V
TA	Operating Temperature Commercial	0	_	70	°C
ТА	Operating Temperature Industrial	-40	_	85	°C
TA	Operating Temperature Military	-55	_	125	°C

### NOTES:

- 1. For  $\overline{RT}/\overline{RS}/\overline{XI}$  input, VIH = 2.6V (commercial).
- For  $\overline{RT}/\overline{RS}/\overline{XI}$  input, VIH = 2.6V (military).
- 2. 1.5V undershoots are allowed for 10ns once per cycle.

# **DC ELECTRICAL CHARACTERISTICS**

(Commercial:  $VCC = 5V \pm 10\%$ ,  $TA = 0^{\circ}C$  to  $+70^{\circ}C$ ; Industrial:  $VCC = 5V \pm 10\%$ ,  $TA = -40^{\circ}C$  to  $+85^{\circ}C$ ; Military:  $VCC = 5V \pm 10\%$ ,  $TA = -55^{\circ}C$  to  $+125^{\circ}C$ )

			IDT7203 <sup>(1)</sup> IDT7204 <sup>(1)</sup> Commercial and Industrial tA = 12, 15, 20, 25, 35, 50 ns			IDT7203 IDT7204 Military <sup>(3)</sup> tA = 20, 30, 40 ns			
Symbol	Parameter	Min.	Тур.	Max.	Min.	Тур.	Max.	Unit	
ILI <sup>(6)</sup>	Input Leakage Current (Any Input)	-1	_	1	-1	_	1	μA	
ILO <sup>(7)</sup>	Output Leakage Current	-10	_	10	-10	_	10	μA	
Vон	Output Logic "1" Voltage IOH = -2mA	2.4	_	_	2.4	_		V	
Vol	Output Logic "0" Voltage IOL = 8mA	_	_	0.4	_	_	0.4	V	
ICC1 <sup>(8,9,10)</sup>	Active Power Supply Current	_	_	120	_	_	150	mA	
ICC2 <sup>(8,10,11)</sup>	Standby Current ( $\overline{R}=\overline{W}=\overline{RS}=\overline{FL}/\overline{RT}=VH$ )	_	_	12	_	_	25	mA	
ICC3 <sup>(8,10,12)</sup>	Power Down Current	_	_	2	_	_	4	mA	
			IDT7205 <sup>(2)</sup> IDT7206 <sup>(2,4)</sup> IDT7207 <sup>(2,4)</sup> IDT7208 <sup>(2,5)</sup> Commercial and Industrial tA = 12, 15, 20, 25, 35, 50 ns		IDT7205 IDT7206 IDT7207 Military tA = 20, 30 ns				
Symbol	Parameter	Min.	Тур.	Max.	Min.	Тур.	Max.	Unit	
ILI <sup>(6)</sup>	Input Leakage Current (Any Input)	-1	-	1	-1	_	1	μA	
ILO <sup>(7)</sup>	Output Leakage Current	-10	_	10	-10	_	10	μA	
Vон	Output Logic "1" Voltage IOH = -2mA	2.4	_	_	2.4	_	_	V	
Vol	Output Logic "0" Voltage IoL = 8mA	—	_	0.4	_	_	0.4	V	
ICC1 <sup>(8,9,10)</sup>	Active Power Supply Current	—	_	120	_	_	150	mA	
ICC2 <sup>(8,10,11)</sup>	Standby Current (RS=FL/RT=VIH)	—	_	12	_	_	25	mA	
ICC3 <sup>(8,10,12)</sup>	Power Down Current	_	_	8	_	_	12	mA	

### NOTES:

- 1. Industrial temperature range product for 15ns and 25ns speed grades are available as a standard device.
- 2. Industrial temperature range product for 25ns speed grade only is available as a standard device. All other speed grades are available by special order.
- 3. Military temperature range product for the 40ns is only available for 7203.
- 4. Commercial temperature range product for the 12ns not available.
- 5. Commercial temperature range product for the 12ns, 15ns and 50ns not available.
- 6. Measurements with 0.4  $\leq$  VIN  $\leq$  Vcc.
- 7.  $\overline{R} \ge V_{IH}$ ,  $0.4 \le V_{OUT} \le V_{CC}$ .
- 8. Tested with outputs open (IOUT = 0).
- 9.  $\overline{R}$  and  $\overline{W}$  toggle at 20 MHz and data inputs switch at 10 MHz.
- 10. Icc measurements are made with outputs open.
- 11. All Inputs = Vcc 0.2V or GND + 0.2V, except  $\overline{R}$  and  $\overline{W}$ , which toggle at 20MHz.
- 12. All Inputs = Vcc 0.2V or GND + 0.2V, except  $\overline{R}$  and  $\overline{W}$  = Vcc -0.2V.

# **AC TEST CONDITIONS**

Input Pulse Levels	GND to 3.0V
Input Rise/Fall Times	5ns
Input Timing Reference Levels	1.5V
Output Reference Levels	1.5V
Output Load	See Figure 1

# CAPACITANCE<sup>(1)</sup> (T<sub>A</sub> = +25°C, f = 1.0 MHz)

CIN <sup>(1)</sup> Input CapacitanceVIN = 0V10pFCOUT <sup>(1,2)</sup> Output CapacitanceVOUT = 0V10pF	5	Symbol	Parameter	Condition	Max.	Unit
Cout <sup>(1,2)</sup> Output Capacitance Vout = 0V 10 pF	(	CIN <sup>(1)</sup>	Input Capacitance	VIN = 0V	10	pF
		COUT <sup>(1,2)</sup>	Output Capacitance	Vout = 0V	10	pF

- NOTES:
- 1. This parameter is sampled and not 100% tested.

2. With output deselected.

5V 1.1KΩ 0.U.T. 680Ω -30pF\* 2661 drw03

or equivalent circuit

Figure 1. Output Load \*Includes jig and scope capacitances.

# AC ELECTRICAL CHARACTERISTICS<sup>(1)</sup>

(Commercial:  $Vcc = 5V \pm 10\%$ ,  $Ta = 0^{\circ}C$  to  $+70^{\circ}C$ ; Industrial:  $Vcc = 5V \pm 10\%$ ,  $Ta = -40^{\circ}C$  to  $+85^{\circ}C$ ; Military:  $Vcc = 5V \pm 10\%$ ,  $Ta = -55^{\circ}C$  to  $+125^{\circ}C$ )

		Com	nercial	Com'l	& Ind'l	Com'l &	Military	Com	nercial	Com'l	& Ind'l	
		IDT7203L12 IDT7204L12 IDT7205L12		IDT720 IDT72 IDT72	IDT7203L15 <sup>(2)</sup> IDT7204L15 <sup>(2)</sup> IDT7205L15 IDT7206L15 IDT7207L15		IDT7203L20 IDT7204L20 IDT7205L20 IDT7206L20 IDT7207L20		IDT7208L20		IDT7203L25 <sup>(2)</sup> IDT7204L25 <sup>(2)</sup> IDT7205L25 <sup>(3)</sup> IDT7206L25 <sup>(3)</sup> IDT7207L25 <sup>(3)</sup> IDT7208L25 <sup>(3)</sup>	
Symbol	Parameters	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Unit
fs	Shift Frequency		50		40		33.3		33.3		28.5	MHz
tRC	Read Cycle Time	20		25		30	_	30		35		ns
tA	Access Time		12		15		20	_	20		25	ns
tRR	Read Recovery Time	8	_	10		10	_	10	_	10		ns
tRPW	Read Pulse Width <sup>(4)</sup>	12	_	15	—	20	—	20	—	25	—	ns
trlz	Read LOW to Data Bus LOW <sup>(5)</sup>	3	—	5	—	5	—	5	—	5	—	ns
twLz	Write HIGH to Data Bus Low-Z <sup>(5,6)</sup>	3	_	5	_	5	_	5	_	5	_	ns
tDV	Data Valid from Read HIGH	5	_	5	_	5	—	5	—	5	_	ns
tRHZ	Read HIGH to Data Bus High-Z <sup>(5)</sup>	—	12	_	15		15		15	_	18	ns
twc	Write Cycle Time	20	_	25	_	30	—	30	—	35	_	ns
twpw	Write Pulse Width <sup>(4)</sup>	12	_	15	_	20	—	20	—	25	_	ns
twr	Write Recovery Time	8	_	10	_	10	_	10	_	10	_	ns
tDS	Data Set-up Time	9	_	11	_	12	_	12	_	15	_	ns
tDH	Data Hold Time	0	_	0	_	0	_	0	_	0	_	ns
trsc	Reset Cycle Time	20	_	25	_	30	_	30	_	35		ns
tRS	Reset Pulse Width <sup>(4)</sup>	12	_	15	_	20	_	20	_	25	_	ns
tRSS	Reset Set-up Time <sup>(5)</sup>	12	_	15	_	20	_	20	_	25	_	ns
trsr	Reset Recovery Time	8	_	10	_	10	_	10	_	10	_	ns
trtc	Retransmit Cycle Time	20	_	25	_	30	_	30	_	35	_	ns
trt	Retransmit Pulse Width <sup>(4)</sup>	12	_	15	_	20	_	20	_	25	_	ns
trts	Retransmit Set-up Time <sup>(5)</sup>	12	_	15	_	20	_	20	_	25	<u> </u>	ns
trtr	Retransmit Recovery Time	8	_	10	_	10	_	10	_	10	_	ns
tefl	Reset to EF LOW	_	12	_	25	_	30	_	30	_	35	ns
thfh, tffh	Reset to HF and FF HIGH	_	17	_	25	_	30	_	30	_	35	ns
trtf	Retransmit LOW to Flags Valid	_	20	_	25	_	30	_	30	_	35	ns
tREF	Read LOW to EF LOW	<u> </u>	12	_	15	_	20	_	20		25	ns
tRFF	Read HIGH to FF HIGH	<u> </u>	14	_	15	<u> </u>	20	_	20	<u> </u>	25	ns
tRPE	Read Pulse Width after EF HIGH	12	_	15		20	_	20	_	25	_	ns
twer	Write HIGH to EF HIGH		12		15		20		20		25	ns
twff	Write LOW to FF LOW	<u> </u>	14	_	15	_	20	_	20		25	ns
twhf	Write LOW to HF Flag LOW	<u> </u>	17	_	25	_	30	_	30		35	ns
tRHF	Read HIGH to HF Flag HIGH	<u> </u>	17	_	25	_	30	_	30		35	ns
twpF	Write Pulse Width after FF HIGH	12		15		20	_	20		25		ns
txol	Read/Write LOW to XO LOW		12		15		20		20		25	ns
txoh	Read/Write HIGH to XO HIGH	<u> </u>	12	_	15		20	_	20		25	ns
txi	XI Pulse Width <sup>(4)</sup>	12		15		20		20		25		ns
txir	XI Recovery Time	8	_	10	_	10	_	10	_	10	_	ns
txis	XI Set-up Time	8	_	10		10		10	_	10		ns

### NOTES:

1. Timings referenced as in AC Test Conditions.

2. Industrial temperature range product for 15ns and 25ns speed grades are available as a standard device.

3. Industrial temperature range product for 25ns speed grade only is available as a standard device. All other speed grades are available by special order.

4. Pulse widths less than minimum are not allowed.

5. Values guaranteed by design, not currently tested. 6. Only applies to read data flow-through mode.

# AC ELECTRICAL CHARACTERISTICS<sup>(1)</sup> (CONTINUED)

(Commercial:  $VCC = 5V \pm 10\%$ ,  $TA = 0^{\circ}C$  to  $+70^{\circ}C$ ; Industrial:  $VCC = 5V \pm 10\%$ ,  $TA = -40^{\circ}C$  to  $+85^{\circ}C$ ; Military:  $VCC = 5V \pm 10\%$ ,  $TA = -55^{\circ}C$  to  $+125^{\circ}C$ )

		Mi	litary	Comn	nercial	Mili	tary	Comn	nercial	Τ
		IDT7. IDT7. IDT7.	IDT7203L30 IDT7204L30 IDT7205L30 IDT7206L30 IDT7207L30		IDT7203L35 IDT7204L35 IDT7205L35 IDT7206L35 IDT7206L35 IDT7208L35		IDT7203L40		IDT7203L50 IDT7204L50 IDT7205L50 IDT7206L50 IDT7207L50	
Symbol	Parameters	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Unit
fs	Shift Frequency	_	25	_	22.22	_	20		15	MHz
tRC	Read Cycle Time	40	—	45	_	50	_	65	_	ns
tA	Access Time		30	_	35	_	40	_	50	ns
tRR	Read Recovery Time	10	_	10	_	10	_	15	_	ns
tRPW	Read Pulse Width <sup>(2)</sup>	30	—	35	_	40	_	50	_	ns
trlz	Read LOW to Data Bus LOW <sup>(3)</sup>	5	_	5	_	5	—	10	—	ns
twlz	Write HIGH to Data Bus Low-Z <sup>(3,4)</sup>	5	—	10	—	10	_	15	_	ns
tDV	Data Valid from Read HIGH	5	—	5	—	5	_	5		ns
tRHZ	Read HIGH to Data Bus High-Z <sup>(3)</sup>		20	_	20	_	25	_	30	ns
twc	Write Cycle Time	40	—	45	—	50	_	65	_	ns
twpw	Write Pulse Width <sup>(2)</sup>	30	—	35	_	40	_	50		ns
twr	Write Recovery Time	10	_	10	—	10	—	15	—	ns
tDS	Data Set-up Time	18	_	18	_	20	_	30	_	ns
tDH	Data Hold Time	0	—	0	_	0	_	5	_	ns
trsc	Reset Cycle Time	40	_	45	_	50	—	65	—	ns
tRS	Reset Pulse Width <sup>(2)</sup>	30	_	35	_	40	_	50	_	ns
trss	Reset Set-up Time <sup>(3)</sup>	30	—	35	_	40	_	50	_	ns
trsr	Reset Recovery Time	10	_	10	—	10	—	15	—	ns
<b>t</b> RTC	Retransmit Cycle Time	40	—	45	_	50	_	65	—	ns
trt	Retransmit Pulse Width <sup>(2)</sup>	30	—	35	_	40	—	50	—	ns
trts	Retransmit Set-up Time <sup>(3)</sup>	30	_	35	—	40	—	50	—	ns
<b>t</b> RTR	Retransmit Recovery Time	10	_	10	_	10	_	15	_	ns
tefl	Reset to EF LOW		40	_	45	—	50	_	65	ns
thfh, tffh	Reset to HF and FF HIGH	—	40	—	45	—	50	—	65	ns
<b>t</b> RTF	Retransmit LOW to Flags Valid		40	_	45	_	50		65	ns
tref	Read LOW to EF LOW		30	_	30	—	35	_	45	ns
trff	Read HIGH to FF HIGH		30	_	30	_	35	_	45	ns
<b>T</b> RPE	Read Pulse Width after EF HIGH	30	_	35	_	40	_	50		ns
twer	Write HIGH to EF HIGH		30		30	_	35		45	ns
twff	Write LOW to FF LOW	-	30	_	30	—	35	_	45	ns
<b>t</b> WHF	Write LOW to HF Flag LOW		40	_	45	_	50	_	65	ns
tRHF	Read HIGH to HF Flag HIGH		40	_	45	_	50	_	65	ns
twpf	Write Pulse Width after FF HIGH	30	—	35	_	40	—	50		ns
txol	Read/Write LOW to XO LOW		30	_	35	_	40	_	50	ns
tхон	Read/Write HIGH to XO HIGH		30	_	35	_	40		50	ns
txı	XI Pulse Width <sup>(2)</sup>	30	_	35	_	40	—	50	_	ns
<b>t</b> XIR	XI Recovery Time	10	_	10	_	10	—	10		ns
txis	XI Set-up Time	10	-	15	_	15	_	15	-	ns

### NOTES:

1. Timings referenced as in AC Test Conditions.

Pulse widths less than minimum are not allowed.
Values guaranteed by design, not currently tested.
Only applies to read data flow-through mode.

# SIGNAL DESCRIPTIONS

### **INPUTS:**

DATA IN (Do-D8) — Data inputs for 9-bit wide data.

# **CONTROLS:**

**RESET** ( $\overline{RS}$ ) — Reset is accomplished whenever the Reset ( $\overline{RS}$ ) input is taken to a LOW state. During reset, both internal read and write pointers are set to the first location. A reset is required after power-up before a write operation can take place. Both the Read Enable ( $\overline{R}$ ) and Write Enable ( $\overline{W}$ ) inputs must be in the HIGH state during the window shown in Figure 2 (i.e. tRSS before the rising edge of  $\overline{RS}$ ) and should not change until tRSR after the rising edge of  $\overline{RS}$ .

WRITE ENABLE ( $\overline{W}$ ) — A write cycle is initiated on the falling edge of this input if the Full Flag ( $\overline{FF}$ ) is not set. Data set-up and hold times must be adhered-to, with respect to the rising edge of the Write Enable ( $\overline{W}$ ). Data is stored in the RAM array sequentially and independently of any on-going read operation.

After half of the memory is filled, and at the falling edge of the next write operation, the Half-Full Flag ( $\overline{\text{HF}}$ ) will be set to LOW, and will remain set until the difference between the write pointer and read pointer is less-than or equal to one-half of the total memory of the device. The Half-Full Flag ( $\overline{\text{HF}}$ ) is then reset by the rising edge of the read operation.

To prevent data overflow, the Full Flag ( $\overline{FF}$ ) will go LOW on the falling edge of the last write signal, which inhibits further write operations. Upon the completion of a valid read operation, the Full Flag ( $\overline{FF}$ ) will go HIGH after tRFF, allowing a new valid write to begin. When the FIFO is full, the internal write pointer is blocked from  $\overline{W}$ , so external changes in  $\overline{W}$  will not affect the FIFO when it is full.

**READENABLE** ( $\overline{R}$ ) — A read cycle is initiated on the falling edge of the Read Enable ( $\overline{R}$ ), provided the Empty Flag ( $\overline{EF}$ ) is not set. The data is accessed on a First-In/First-Outbasis, independent of any ongoing write operations. After Read Enable ( $\overline{R}$ ) goes HIGH, the Data Outputs (Oo through Q8) will return to a highimpedance condition until the next Read operation. When all the data has been read from the FIFO, the Empty Flag ( $\overline{EF}$ ) will go LOW, allowing the "final" read cycle but inhibiting further read operations, with the data outputs remaining in a highimpedance state. Once a valid write operation has been accomplished, the Empty Flag ( $\overline{EF}$ ) will go HIGH after twEF and a valid Read can then begin. When the FIFO is empty, the internal read pointer is blocked from  $\overline{R}$  so external changes will not affect the FIFO when it is empty.

**FIRST LOAD/RETRANSMIT (FL/RT)** — This is a dual-purpose input. In the Depth Expansion Mode, this pin is grounded to indicate that it is the first device

loaded (see Operating Modes). The Single Device Mode is initiated by grounding the Expansion In ( $\overline{XI}$ ).

The IDT7203/7204/7205/7206/7207/7208 can be made to retransmit data when the Retransmit Enable Control ( $\overline{RT}$ ) input is pulsed LOW. A retransmit operation will set the internal read pointer to the first location and will not affect the write pointer. The status of the Flags will change depending on the relative locations of the read and write pointers. Read Enable ( $\overline{R}$ ) and Write Enable ( $\overline{W}$ ) must be in the HIGH state during retransmit. This feature is useful when less than 2,048/4,096/8,192/16,384/32,768/65,536 writes are performed between resets. The retransmit feature is not compatible with the Depth Expansion Mode.

**EXPANSION IN** ( $\overline{XI}$ ) — This input is a dual-purpose pin. Expansion In ( $\overline{XI}$ ) is grounded to indicate an operation in the single device mode. Expansion In ( $\overline{XI}$ ) is connected to Expansion Out ( $\overline{XO}$ ) of the previous device in the Depth Expansion or Daisy-Chain Mode.

# **OUTPUTS:**

FULL FLAG ( $\overline{FF}$ ) — The Full Flag ( $\overline{FF}$ ) will go LOW, inhibiting further write operations, when the device is full. If the read pointer is not moved after Reset ( $\overline{RS}$ ), the Full Flag ( $\overline{FF}$ ) will go LOW after 2,048/4,096/8,192/16,384/32,768/65,536 writes.

**EMPTY FLAG** ( $\overline{EF}$ ) — The Empty Flag ( $\overline{EF}$ ) will go LOW, inhibiting further read operations, when the read pointer is equal to the write pointer, indicating that the device is empty.

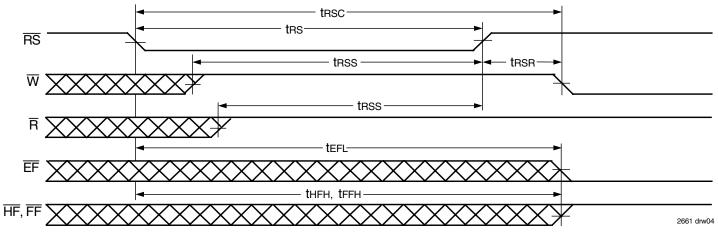
**EXPANSION OUT/HALF-FULL FLAG (\overline{XO}/\overline{HF})**— This is a dual-purpose output. In the single device mode, when Expansion In ( $\overline{XI}$ ) is grounded, this output acts as an indication of a half-full memory.

After half of the memory is filled, and at the falling edge of the next write operation, the Half-Full Flag ( $\overline{HF}$ ) will be set to LOW and will remain set until the difference between the write pointer and read pointer is less than or equal to one half of the total memory of the device. The Half-Full Flag ( $\overline{HF}$ ) is then reset by the rising edge of the read operation.

In the Depth Expansion Mode, Expansion In  $(\overline{XI})$  is connected to Expansion Out  $(\overline{XO})$  of the previous device. This output acts as a signal to the next device in the Daisy Chain by providing a pulse to the next device when the previous device reaches the last location of memory. There will be an  $\overline{XO}$  pulse when the Write pointer reaches the last location of memory, and an additional  $\overline{XO}$  pulse when the Read pointer reaches the last location of memory.

**DATA OUTPUTS (Q0-Q8)** — Q0-Q8 are data outputs for 9-bit wide data. These outputs are in a high-impedance condition whenever Read ( $\overline{R}$ ) is in a HIGH state.

# IDT7203/7204/7205/7206/7207/7208 CMOS ASYNCHRONOUS FIFO 2,048 x 9, 4,096 x 9, 8,192 x 9, 16,384 x 9, 32,768 x 9 and 65,536 x 9



NOTE:

1.  $\overline{W}$  and  $\overline{R}$  = VIH around the rising edge of  $\overline{RS}$ .

Figure 2. Reset

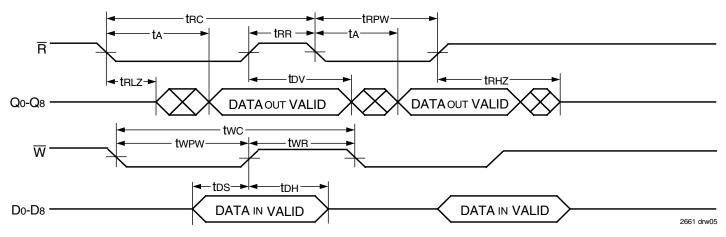


Figure 3. Asynchronous Write and Read Operation

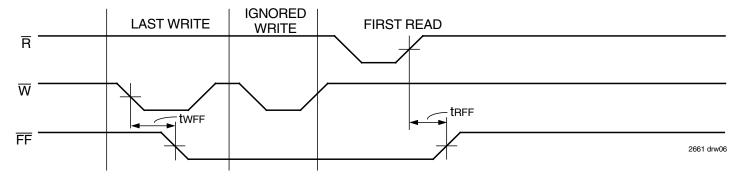


Figure 4. Full Flag Timing From Last Write to First Read

### IDT7203/7204/7205/7206/7207/7208 CMOS ASYNCHRONOUS FIFO 2,048 x 9, 4,096 x 9, 8,192 x 9, 16,384 x 9, 32,768 x 9 and 65,536 x 9

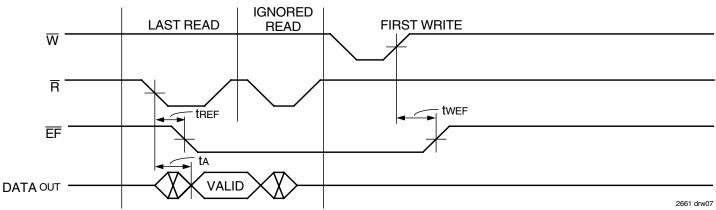
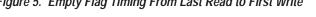
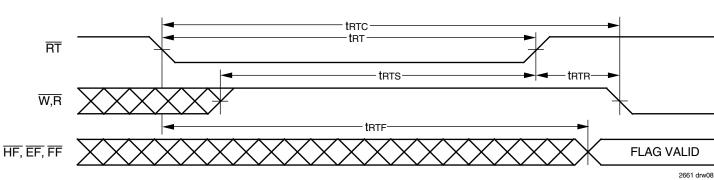


Figure 5. Empty Flag Timing From Last Read to First Write





NOTE: 1.  $\overline{EF}$ ,  $\overline{FF}$  and  $\overline{HF}$  may change status during Retransmit, but flags will be valid at trtc.

Figure 6. Retransmit

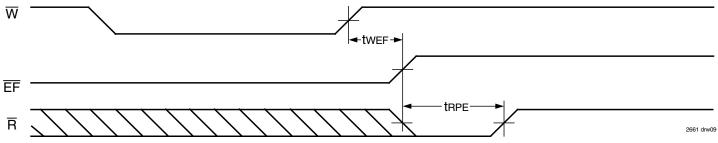


Figure 7. Minimum Timing for an Empty Flag Coincident Read Pulse.

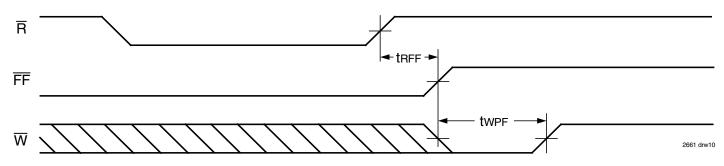


Figure 8. Minimum Timing for a Full Flag Coincident Write Pulse.



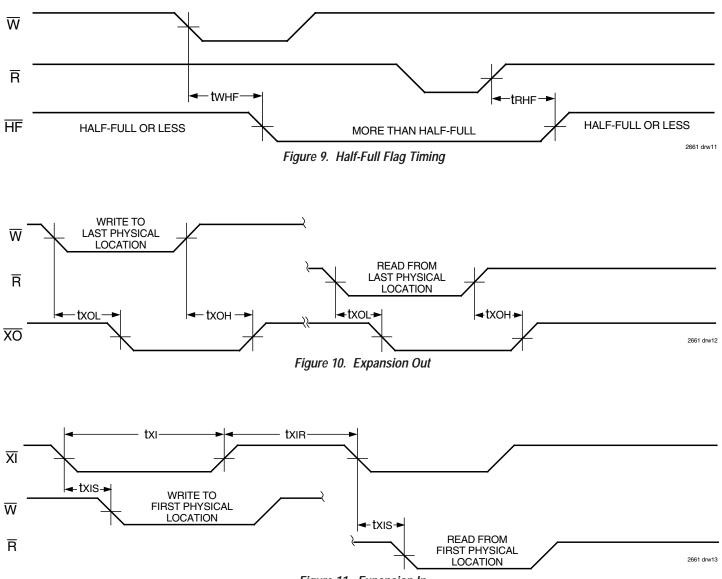


Figure 11. Expansion In

# **OPERATING MODES:**

Care must be taken to assure that the appropriate flag is monitored by each system (i.e. FF is monitored on the device where Wis used; EF is monitored on the device where Ris used). For additional information on the IDT7203/7204/7205/7206/7207, refer to Tech Note 8: *Operating FIFOs on Full and Empty Boundary Conditions* and Tech Note 6: *Designing with FIFOs.* 

### Single Device Mode

A single IDT7203/7204/7205/7206/7207/7208 may be used when the application requirements are for 2,048/4,096/8,192/16,384/32,768/65,536 words or less. These FIFOs are in a Single Device Configuration when the Expansion In  $(\overline{XI})$  control input is grounded (see Figure 12).

### **Depth Expansion**

These FIFOs can easily be adapted to applications when the requirements are for greater than 2,048/4,096/8,192/16,384/32,768/65,536 words. Figure 14 demonstrates Depth Expansion using three IDT7203/7204/7205/ 7206/7207/7208s. Any depth can be attained by adding additional IDT7203/ 7204/7205/7206/7207/7208s. These devices operate in the Depth Expansion mode when the following conditions are met:

- 1. The first device must be designated by grounding the First Load (FL) control input.
- 2. All other devices must have  $\overline{FL}$  in the HIGH state.
- 3. The Expansion Out (XO) pin of each device must be tied to the Expansion In (XI) pin of the next device. See Figure 14.
- External logic is needed to generate a composite Full Flag (FF) and Empty Flag (EF). This requires the ORing of all EFs and ORing of all FFs (i.e. all must be set to generate the correct composite FF or EF). See Figure 14.
- 5. The Retransmit (RT) function and Half-Full Flag (HF) are not available in the Depth Expansion Mode.

For additional information on the IDT7203/7204/7205/7206/7207, refer to Tech Note 9: *Cascading FIFOs or FIFO Modules.* 

# IDT7203/7204/7205/7206/7207/7208 CMOS ASYNCHRONOUS FIFO 2,048 x 9, 4,096 x 9, 8,192 x 9, 16,384 x 9, 32,768 x 9 and 65,536 x 9

# **USAGE MODES:**

### Width Expansion

Word width may be increased simply by connecting the corresponding input control signals of multiple devices. Status flags (EF, FF and HF) can be detected from any one device. Figure 13 demonstrates an 18-bit word width by using two IDT7203/7204/7205/7206/7207/7208s. Any word width can be attained by adding additional IDT7203/7204/7205/7206/7207/7208s (Figure 13).

### **Bidirectional Operation**

Applications which require data buffering between two systems (each system capable of Read and Write operations) can be achieved by pairing IDT7203/7204/7205/7206/7207/7208s as shown in Figure 16. Both Depth Expansion and Width Expansion may be used in this mode.

### Data Flow-Through

NOTE:

Two types of flow-through modes are permitted, a read flow-through and write flow-through mode. For the read flow-through mode (Figure 17), the

FIFO permits a reading of a single word after writing one word of data into an empty FIFO. The data is enabled on the bus in (twEF + tA) ns after the rising edge of  $\overline{W}$ , called the first write edge, and it remains on the bus until the  $\overline{R}$  line is raised from LOW-to-HIGH, after which the bus would go into a three-state mode after tRHz ns. The  $\overline{EF}$  line would have a pulse showing temporary deassertion and then would be asserted.

In the write flow-through mode (Figure 18), the FIFO permits the writing of a single word of data immediately after reading one word of data from a full FIFO. The  $\overline{R}$  line causes the  $\overline{FF}$  to be deasserted but the  $\overline{W}$  line being LOW causes it to be asserted again in anticipation of a new data word. On the rising edge of  $\overline{W}$ , the new word is loaded in the FIFO. The  $\overline{W}$  line must be toggled when  $\overline{FF}$  is not asserted to write new data in the FIFO and to increment the write pointer.

### **Compound Expansion**

The two expansion techniques described above can be applied together in a straightforward manner to achieve large FIFO arrays (see Figure 15).

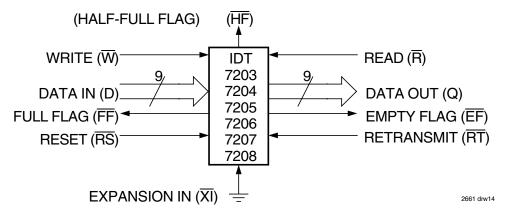
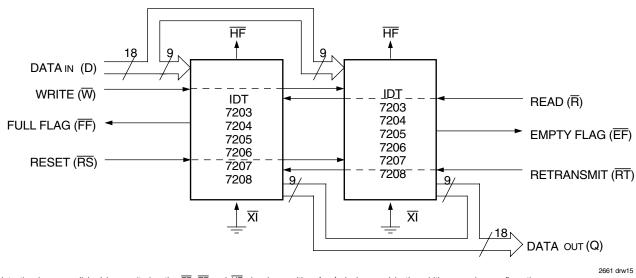


Figure 12. Block Diagram of 2,048 x 9, 4,096 x 9, 8,192 x 9, 16,384 x 9, 32,768 x 9, 65,536 x 9 FIFO Used in Single Device Mode



1. Flag detection is accomplished by monitoring the FF, EF and HF signals on either (any) device used in the width expansion configuration. Do not connect any output signals together.

Figure 13. Block Diagram of 2,048 x 18, 4,096 x 18, 8,192 x 18, 16,384 x 18, 32,768 x 18, 65,536 x 18 FIFO Memory Used in Width Expansion Mode

# TRUTH TABLES TABLE 1 – RESET AND RETRANSMIT

SINGLE DEVICE CONFIGURATION/WIDTH EXPANSION MODE

	Inputs			Interna	Outputs			
Mode	RS	FL/RT	Xī	Read Pointer	Write Pointer	ĒĒ	FF	HF
Reset	0	Х	0	Location Zero	Location Zero	0	1	1
Retransmit	1	0	0	Location Zero	Unchanged	Х	Х	Х
Read/Write	1	1	0	Increment <sup>(1)</sup>	Increment <sup>(1)</sup>	Х	Х	Х

NOTE:

1. Pointer will Increment if flag is HIGH.

# **TABLE 2 – RESET AND FIRST LOAD**

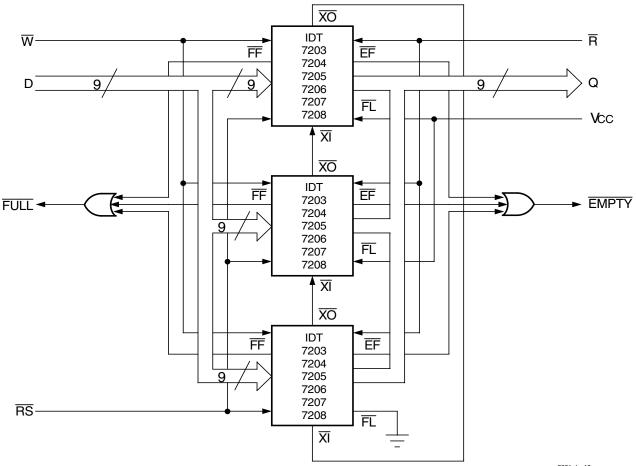
DEPTH EXPANSION/COMPOUND EXPANSION MODE

	Inputs			Interna	al Status	Outputs		
Mode	RS	FL/RT	Xī	Read Pointer	Write Pointer	ĒĒ	FF	
Reset First Device	0	0	(1)	Location Zero	Location Zero	0	1	
Reset All Other Devices	0	1	(1)	Location Zero	Location Zero	0	1	
Read/Write	1	Х	(1)	Х	Х	Х	Х	

#### NOTES:

1.  $\overline{XI}$  is connected to  $\overline{XO}$  of previous device. See Figure 14.

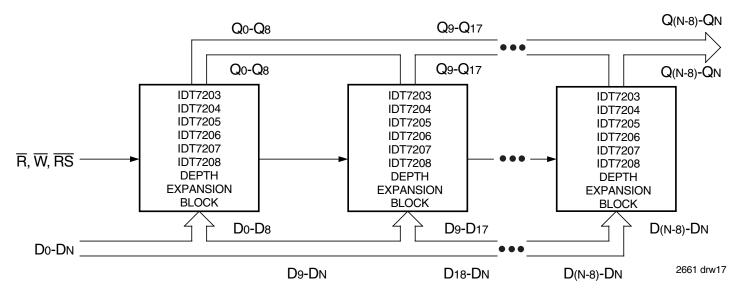
2. RS = Reset Input, FL/RT = First Load/Retransmit, EF = Empty Flag Output, FF = Full Flag Output, XI = Expansion Input, HF = Half-Full Flag Output



2661 drw16

Figure 14. Block Diagram of 6,144 x 9, 12,288 x 9, 24,576 x 9, 49,152 x 9, 98,304 x 9, 196,608 x 9 FIFO Memory (Depth Expansion)

# IDT7203/7204/7205/7206/7207/7208 CMOS ASYNCHRONOUS FIFO 2,048 x 9, 4,096 x 9, 8,192 x 9, 16,384 x 9, 32,768 x 9 and 65,536 x 9



#### NOTES:

1. For depth expansion block see section on Depth Expansion and Figure 14.

2. For Flag detection see section on Width Expansion and Figure 13..



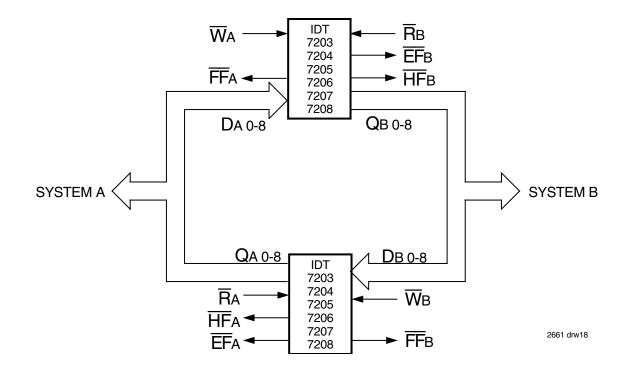
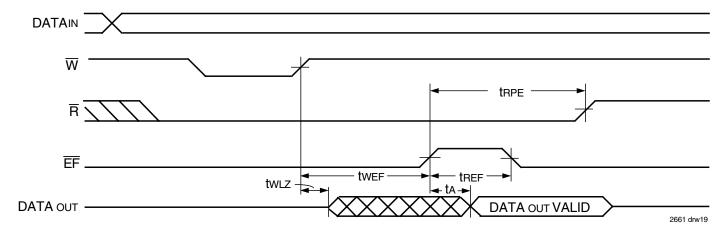
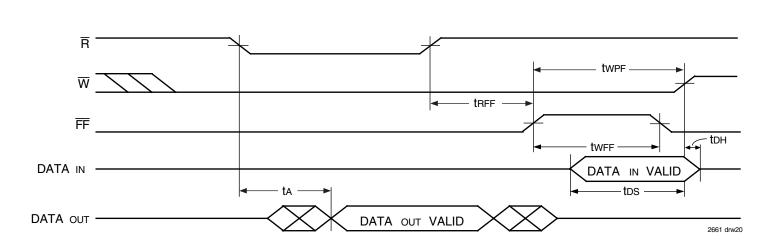


Figure 16. Bidirectional FIFO Operation

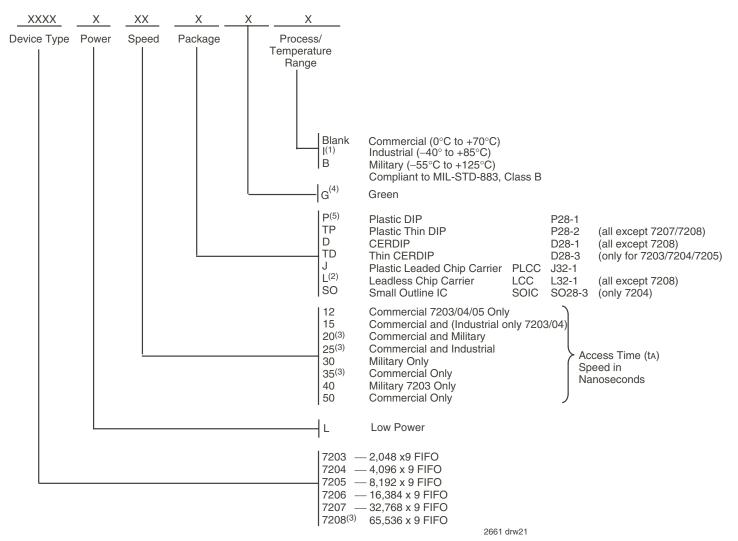








# **ORDERING INFORMATION**



#### NOTES:

- 1. Industrial temperature range product for 15ns and 25ns speed grades are available as a standard device for IDT7203/7204, and 25ns speed grade only is available as a standard device for IDT7205/7206/7207/7208. All other speed grades are available by special order.
- 2. The LCC is only available in the military temperature range.
- 3. The IDT7208 is only available in commercial speed grades of 20, 25 and 35 ns.
- 4. Green parts are available. For specific speeds and packages contact your local sales office.
- 5. For "P", Plastic Dip, when ordering green package, the suffix is "PDG".

### **DATA SHEET HISTORY**

05/10/2001	pgs.	2, 3, 4, 5, 11 and 14.
05/30/2001	pg.	2.
04/03/2006	pgs.	1 and 14.
10/22/2008	pg.	14.
06/11/2009	pgs.	4 and 5.



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